74AUP1G332

Low-power 3-input OR-gate

Rev. 8 — 18 July 2023

Product data sheet

1. General description

The 74AUP1G332 is a single 3-input OR gate. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- · High noise immunity
- · Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range Name Description							
74AUP1G332GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2				
74AUP1G332GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886				
74AUP1G332GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	<u>SOT1115</u>				
74AUP1G332GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				



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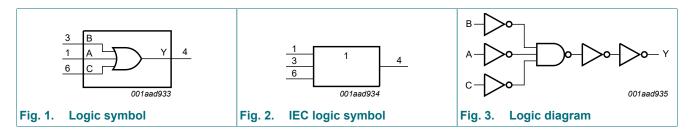
4. Marking

Table 2. Marking

Type number	Marking code [1]
74AUP1G332GW	aG
74AUP1G332GM	aG
74AUP1G332GN	aG
74AUP1G332GS	aG

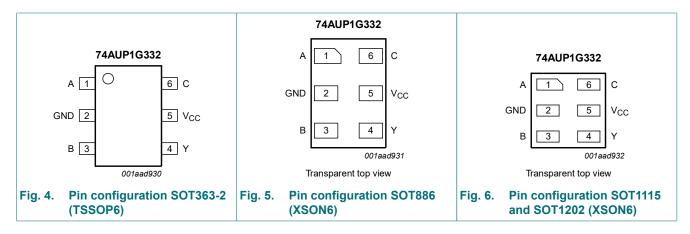
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
A	1	data input A
GND	2	ground (0 V)
В	3	data input B
Υ	4	data output Y
V _{CC}	5	supply voltage
С	6	data input C

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7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$

Input	Output		
Α	В	С	Υ
Н	X	Х	Н
X	Н	X	Н
X	Х	Н	Н
L	L	L	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1] -0.5	+4.6	V
lok	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1] -0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	-	250	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

^[2] For SOT363-2 (TSSOP6) package: P_{tot} derates linearly with 3.7 mW/K above 83 °C.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

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10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC}$ - 0.6 V; $I_O = 0$ A; $V_{CC} = 3.3$ V; One input at V_{CC} - 0.6 V, other inputs at V_{CC} or GND	-	-	40	μА
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_{I} = GND or V_{CC}	-	0.8	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μΑ
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μΑ
ΔI _{CC}	additional supply current	V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V; One input at V_{CC} - 0.6 V, other inputs at V_{CC} or GND	-	-	50	μΑ

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.75	μA
Δl _{OFF}	additional power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μΑ
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μΑ
ΔI _{CC}	additional supply current	V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V; One input at V_{CC} - 0.6 V, other inputs at V_{CC} or GND	-	-	75	μΑ

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11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8.

Symbol	Parameter	Conditions		T,	_{amb} = 25 '	°C	T _{amb} = -40 °C to +85 °C		T _{ar} -40 °C to	_{nb} = o +125 °C	Unit
				Min	Typ [1]	Max	Min	Max	Min	Max	
C _L = 5 p	F										
t _{pd}	propagation	A, B and C to Y; see Fig. 7	[2]								
	delay	V _{CC} = 0.8 V		-	17.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		2.3	5.2	10.2	2.0	10.3	2.0	10.3	ns
		V _{CC} = 1.4 V to 1.6 V		1.7	3.7	6.0	1.9	6.4	1.9	6.6	ns
		V _{CC} = 1.65 V to 1.95 V		1.6	3.0	4.7	1.4	5.2	1.4	5.4	ns
		V _{CC} = 2.3 V to 2.7 V		1.4	2.3	3.3	1.2	3.7	1.2	3.9	ns
		V _{CC} = 3.0 V to 3.6 V		1.2	2.1	2.9	1.1	3.1	1.1	3.3	ns
C _L = 10	pF										
t _{pd}	propagation	A, B and C to Y; see Fig. 7	[2]								
	delay	V _{CC} = 0.8 V		-	17.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		2.5	6.1	11.9	2.4	12.0	2.4	12.0	ns
		V _{CC} = 1.4 V to 1.6 V		2.2	4.3	7.1	2.0	7.3	2.0	7.6	ns
		V _{CC} = 1.65 V to 1.95 V		2.1	3.5	5.4	1.9	5.8	1.9	6.1	ns
		V _{CC} = 2.3 V to 2.7 V		1.7	2.9	4.0	1.5	4.5	1.5	4.7	ns
		V _{CC} = 3.0 V to 3.6 V		1.5	2.6	3.7	1.4	3.9	1.4	4.1	ns
C _L = 15	pF										
t _{pd}	propagation	A, B and C to Y; see Fig. 7	[2]								
	delay	V _{CC} = 0.8 V		-	23.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		2.9	6.9	13.5	2.7	13.6	2.7	13.6	ns
		V _{CC} = 1.4 V to 1.6 V		2.5	4.9	7.8	2.4	8.5	2.4	8.8	ns
		V _{CC} = 1.65 V to 1.95 V		2.2	4.0	6.2	2.1	6.8	2.1	7.1	ns
		V _{CC} = 2.3 V to 2.7 V		2.0	3.3	4.7	1.6	5.2	1.6	5.4	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.9	3.1	4.2	1.7	4.5	1.7	4.8	ns
$C_{L} = 30$	pF										
t_{pd}	propagation	A, B and C to Y; see Fig. 7	[2]								
	delay	V _{CC} = 0.8 V		-	36.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.6	9.2	17.9	3.5	18.4	3.5	18.7	ns
		V _{CC} = 1.4 V to 1.6 V		3.2	6.4	10.4	3.3	11.4	3.3	11.9	ns
		V _{CC} = 1.65 V to 1.95 V		3.0	5.3	8.3	2.9	9.1	2.9	9.6	ns
		V _{CC} = 2.3 V to 2.7 V		2.8	4.4	6.2	1.6	6.7	1.6	7.1	ns
		V _{CC} = 3.0 V to 3.6 V		2.6	4.2	5.5	1.4	6.4	1.4	6.7	ns

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Symbol	Parameter	Conditions	T _{amb} = 25 °C				T _{amb} = T _{amb} = -40 °C to +125 °C		_{nb} = 0 +125 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C _L = 5 p	F, 10 pF, 15 pF	and 30 pF								
C _{PD}	1 -	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3]								
	dissipation capacitance	V _{CC} = 0.8 V	-	2.5	-	-	-	-	-	pF
	capacitarioc	V _{CC} = 1.1 V to 1.3 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.5	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.0	-	-	-	-	-	pF

- [1] All typical values are measured at nominal V_{CC}.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] \dot{C}_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

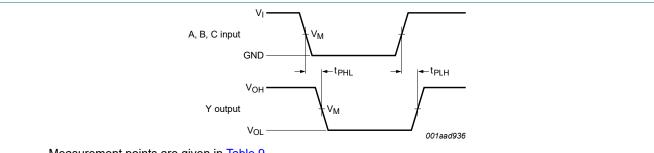
f_o = output frequency in MHz;

C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

11.1. Waveform and test circuit



Measurement points are given in <u>Table 9</u>.

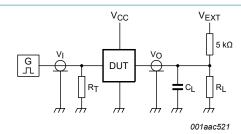
Logic levels: V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig. 7. Input A, B and C to output Y propagation delay times

Table 9. Measurement points

Supply voltage	Output	Input				
V _{CC}	V _M	V_{M} V_{I} $t_{r} = t_{f}$				
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns		

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Test data is given in Table 10.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 8. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 k Ω . For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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12. Package outline

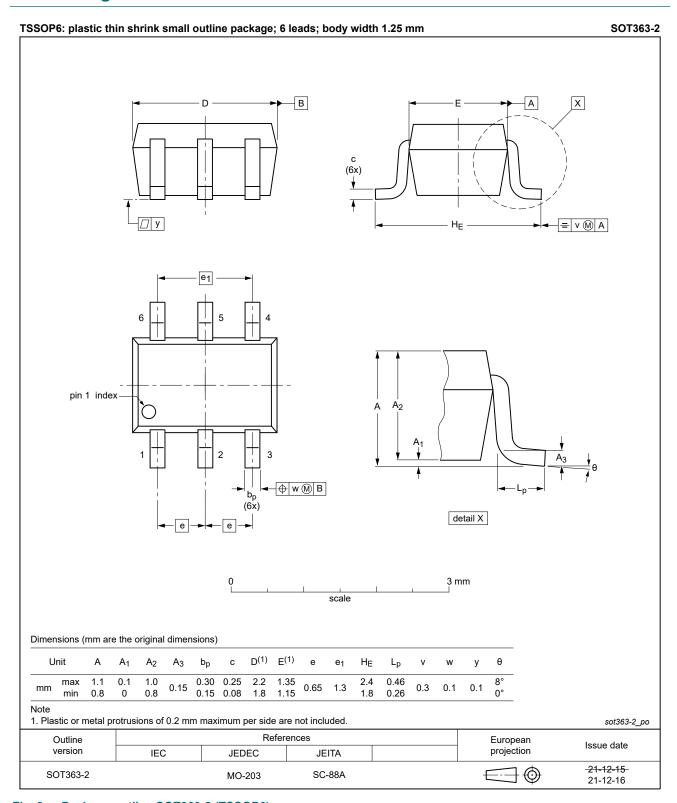


Fig. 9. Package outline SOT363-2 (TSSOP6)

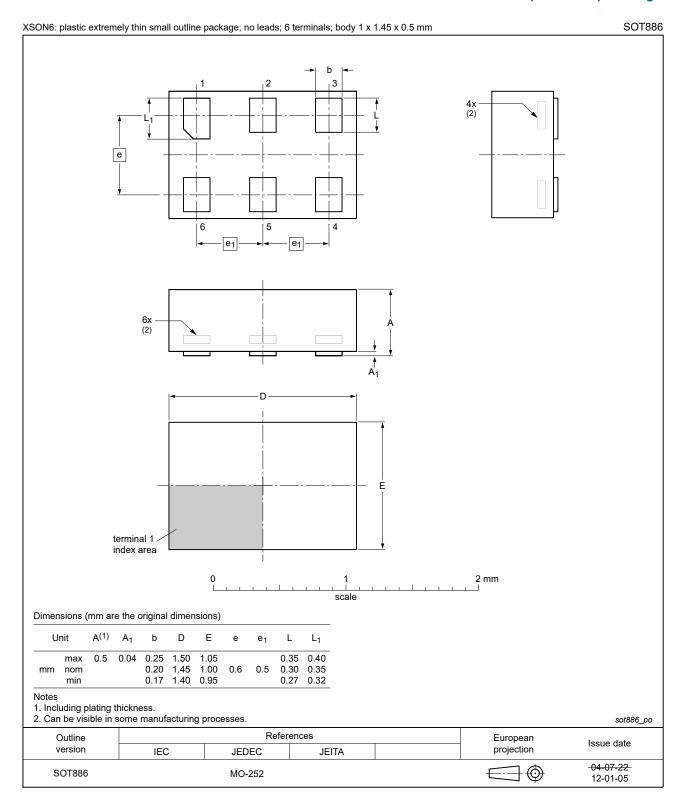


Fig. 10. Package outline SOT886 (XSON6)

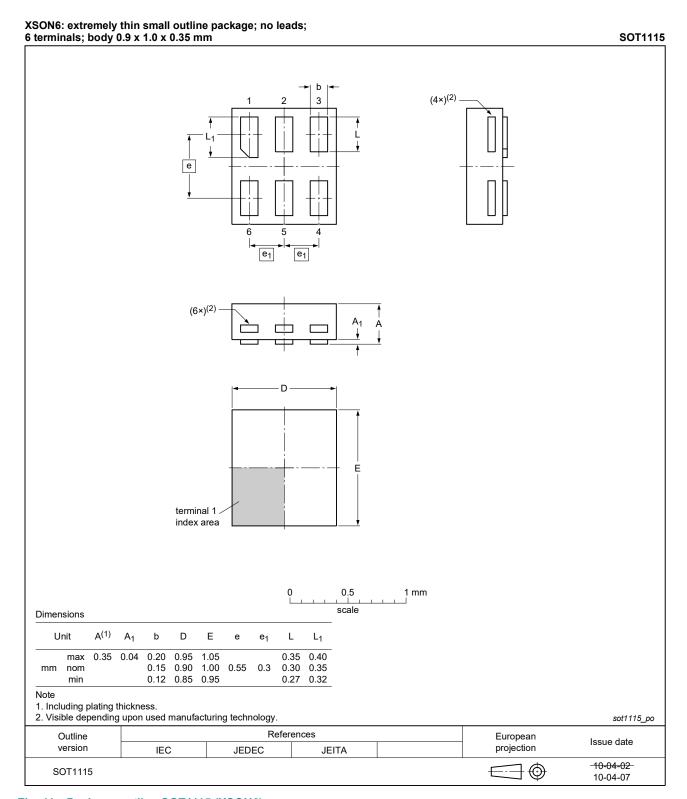


Fig. 11. Package outline SOT1115 (XSON6)

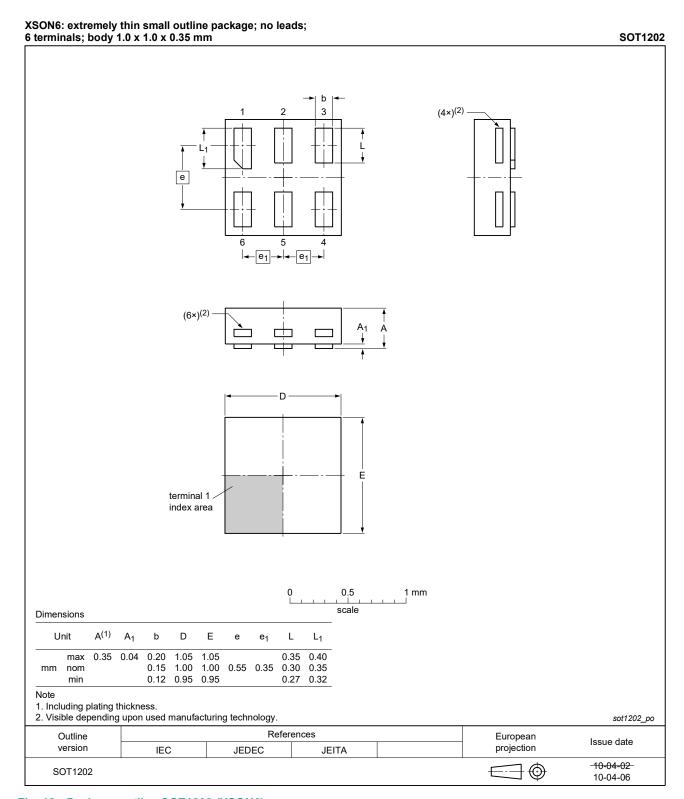


Fig. 12. Package outline SOT1202 (XSON6)

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13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G332 v.8	20230718	Product data sheet	-	74AUP1G332 v.7
Modifications:	<u>Section 2</u> : I	ESD specification updated	according to the la	atest JEDEC standard.
74AUP1G332 v.7	20220120	Product data sheet	-	74AUP1G332 v.6
Modifications:		ind <u>Section 2</u> updated. OT363 (SC-88) changed to	o SOT363-2 (TSS	DP6).
74AUP1G332 v.6	20201203	Product data sheet	-	74AUP1G332 v.5
Modifications:	guidelines • Legal texts • Type numb	of this data sheet has bee of Nexperia. have been adapted to the er 74AUP1G332GF (SOT erating values for P _{tot} total	new company nar 891 / XSON6) rem	ne where appropriate. oved.
74AUP1G332 v.5	20120704	Product data sheet	-	74AUP1G332 v.4
Modifications:	Package or	utline drawing of SOT886 ((Fig. 10) modified.	
74AUP1G332 v.4	20111125	Product data sheet	-	74AUP1G332 v.3
	20111125 • Legal page		-	74AUP1G332 v.3
74AUP1G332 v.4 Modifications: 74AUP1G332 v.3			-	74AUP1G332 v.3 74AUP1G332 v.2
Modifications:	Legal page	s updated.	-	

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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